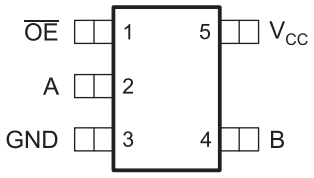
具有 5V 容差的电平转换器的单路 FET 2.5V/3.3V 低电压总线开关

查询样品: SN74CB3T1G125-Q1

特性

- 符合汽车应用要求
- 输出电压转换跟踪 V_{CC}
- 在所有数据 I/O 端口上支持混合模式信号运行
  - 通过 3.3 V V_{CC} 提供 5 V 输入与低至 3.3 V 的输出电平转换
  - 通过 2.5 V V_{CC} 提供 5 V/3.3 V 输入与低至 2.5 V 的输出电平转换
- 支持器件上电与断电的 5 V 容差 I/O
- 支持近零传播延迟的双向数据流
- 低导通阻抗 (r_{on}) 特性（r_{on} = 5 Ω 典型值）
- 低输入 / 输出电容可最大限度地减少加载（$C_{io(OFF)}$ = 5 pF 典型值）
- 数据与控制输入提供负脉冲信号钳位二极管
- 低功耗（I_{CC} = 20 μA 最大值）
- V_{CC} 工作电压范围：2.3 V 至 3.6 V
- 数据 I/O 支持 0 至 5 V 信号级（0.8 V、1.2 V、1.5 V、1.8 V、2.5 V、3.3 V、5 V）
- 可通过 TTL 或 5 V/3.3 V CMOS 输出驱动控制输入
- I_{off} 支持部分断电模式工作
- 支持数字应用：电平转换、USB 接口、总线隔离
- 是低功耗便携式应用的理想选择

DCK PACKAGE
(TOP VIEW)



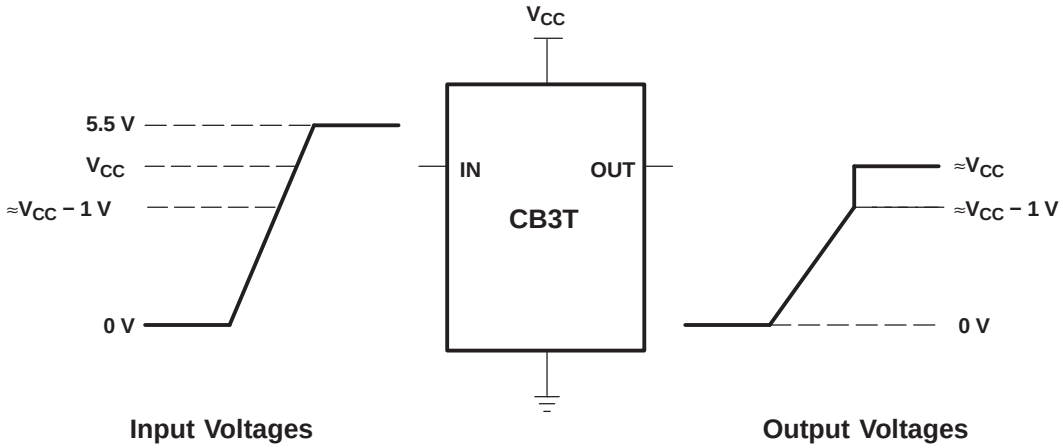
说明

SN74CB3T1G125-Q1 是支持低导通电阻 (r_{on}) 的 高速TTL兼容 FET 总线开关，支持最小传播延迟。 该器件提供可跟踪 V_{CC} 的电压转换，能够在所有数据 I/O 端口上全面支持混合模式信号运行。 SN74CB3T1G125-Q1 支持系统使用 5 V TTL、3.3 V LVTTL 与 2.5 V CMOS 开关标准，以及用户定义开关电平（见图 1）。

SN74CB3T1G125-Q1 是一个具有单一输出使能 ($\overline{OE}$) 输入的 1 -位总线开关。 $\overline{OE}$ 为低时，总线开关打开，A 端口连接至 B 端口，可在两个端口之间实现双向数据流。 $\overline{OE}$ 为高时，总线开关关闭，A 与 B 端口之间存在高阻抗状态。

该器件的技术规格针对采用 I_{off} 的部分断电应用而全面拟订。 I_{off} 特性可在断电时防止损坏电流通过器件回流。 该器件可在关闭时提供隔离。

为了确保加电或断电期间的高阻抗状态，$\overline{OE}$ 应通过一个上拉电阻器连接至 V_{CC}；该电阻器的最小值由驱动器的电流吸收能力来决定。



NOTE A: If the input high voltage (V_{IH}) level is greater than or equal to V_{CC} – 1 V, and less than or equal to 5.5 V, then the output high voltage (V_{OH}) level will be equal to approximately the V_{CC} voltage level.

图 **1.** 典型 **DC** 电压转换特点

ORDERING INFORMATION

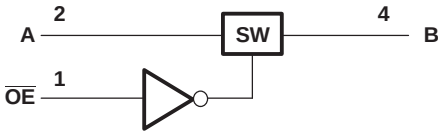
T_A	PACKAGE(1)		ORDERABLE PART NUMBER	TOP-SIDE MARKING(2)
–40°C to 125°C	SOT (SC-70) – DCK	Reel of 3000	CCB3T1G125QDCKRQ1	72_

(1) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.
(2) The actual top-side marking has one additional character that designates the assembly/test site.

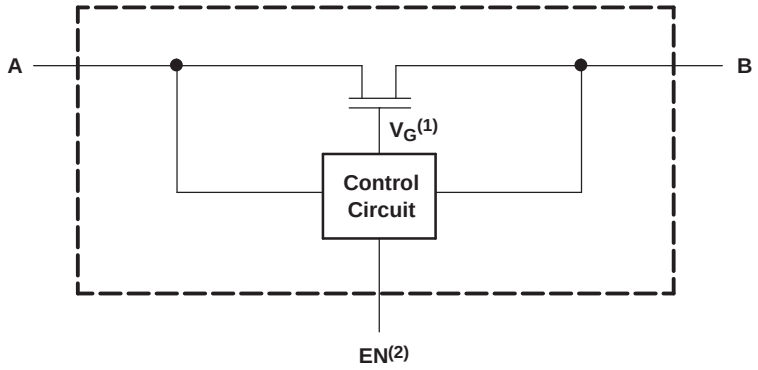
FUNCTION TABLE

INPUT $\overline{OE}$	INPUT/OUTPUT A	FUNCTION
L	B	A port = B port
H	Z	Disconnect

LOGIC DIAGRAM (POSITIVE LOGIC)



SIMPLIFIED SCHEMATIC, EACH FET SWITCH (SW)



(1) Gate voltage (V_G) is equal to approximately $V_{CC} + V_T$ when the switch is ON and $V_I > V_{CC} + V_T$.
(2) EN is the internal enable signal applied to the switch.

ABSOLUTE MAXIMUM RATINGS(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CC}	Supply voltage range		–0.5	7	V
V_{IN}	Control input voltage range(2) (3)		–0.5	7	V
$V_{I/O}$	Switch I/O voltage range(2) (3) (4)		–0.5	7	V
I_{IK}	Control input clamp current	$V_{IN} < 0$		–50	mA
$I_{I/OK}$	I/O port clamp current	$V_{I/O} < 0$		–50	mA
I_{IO}	ON-state switch current(5)			±128	mA
	Continuous current through V_{CC} or GND			±100	mA
θ_{JA}	Package thermal impedance(6)	DCK package		252	°C/W
T_{stg}	Storage temperature range		–65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) All voltages are with respect to ground, unless otherwise specified.
(3) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
(4) V_I and V_O are used to denote specific conditions for $V_{I/O}$.
(5) I_I and I_O are used to denote specific conditions for $I_{I/O}$.
(6) The package thermal impedance is calculated in accordance with JESD 51-7.

RECOMMENDED OPERATING CONDITIONS(1)

			MIN	MAX	UNIT
V_{CC}	Supply voltage		2.3	3.6	V
V_{IH}	High-level control input voltage	V_{CC} = 2.3 V to 2.7 V	1.7	5.5	V
		V_{CC} = 2.7 V to 3.6 V	2	5.5	
V_{IL}	Low-level control input voltage	V_{CC} = 2.3 V to 2.7 V	0	0.7	V
		V_{CC} = 2.7 V to 3.6 V	0	0.8	
$V_{I/O}$	Data input/output voltage		0	5.5	V
T_A	Operating free-air temperature		–40	125	°C

(1) All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

ELECTRICAL CHARACTERISTICS(1)

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP(2)	MAX	UNIT
V_{IK}		V_{CC} = 3 V, I_I = –18 mA				–1.2	V
V_{OH}		See Figure 3 and Figure 4					
I_{IN}	Control inputs	V_{CC} = 3.6 V, V_{IN} = 3.6 V to 5.5 V or GND				±10	µA
I_I		V_{CC} = 3.6 V, Switch ON, V_{IN} = V_{CC} or GND	V_I = V_{CC} – 0.7 V to 5.5 V			±20	µA
			V_I = 0.7 V to V_{CC} – 0.7 V			–40	
			V_I = 0 to 0.7 V			±5	
I_{OZ} (3)		V_{CC} = 3.6 V, V_O = 0 to 5.5 V, V_I = 0, Switch OFF, V_{IN} = V_{CC} or GND				±10	µA
I_{off}		V_{CC} = 0, V_O = 0 to 5.5 V, V_I = 0				10	µA
I_{CC}		V_{CC} = 3.6 V, $I_{I/O}$ = 0, Switch ON or OFF, V_{IN} = V_{CC} or GND	V_I = V_{CC} or GND			20	µA
			V_I = 5.5 V			20	
ΔI_{CC} (4)	Control inputs	V_{CC} = 3 V to 3.6 V, One input at V_{CC} – 0.6 V, Other inputs at V_{CC} or GND				300	µA
C_{in}	Control inputs	V_{CC} = 3.3 V, V_{IN} = V_{CC} or GND			3		pF
$C_{io(OFF)}$		V_{CC} = 3.3 V, $V_{I/O}$ = 5.5 V, 3.3 V, or GND, Switch OFF, V_{IN} = V_{CC} or GND			5		pF
$C_{io(ON)}$		V_{CC} = 3.3 V, Switch ON, V_{IN} = V_{CC} or GND	$V_{I/O}$ = 5.5 V or 3.3 V		4		pF
			$V_{I/O}$ = GND		12		
r_{on} (5)		V_{CC} = 2.3 V, TYP at V_{CC} = 2.5 V, V_I = 0	I_O = 24 mA		5	10	Ω
			I_O = 16 mA		5	10	
		V_{CC} = 3 V, V_I = 0	I_O = 24 mA		5	9	
			I_O = 16 mA		5	9	

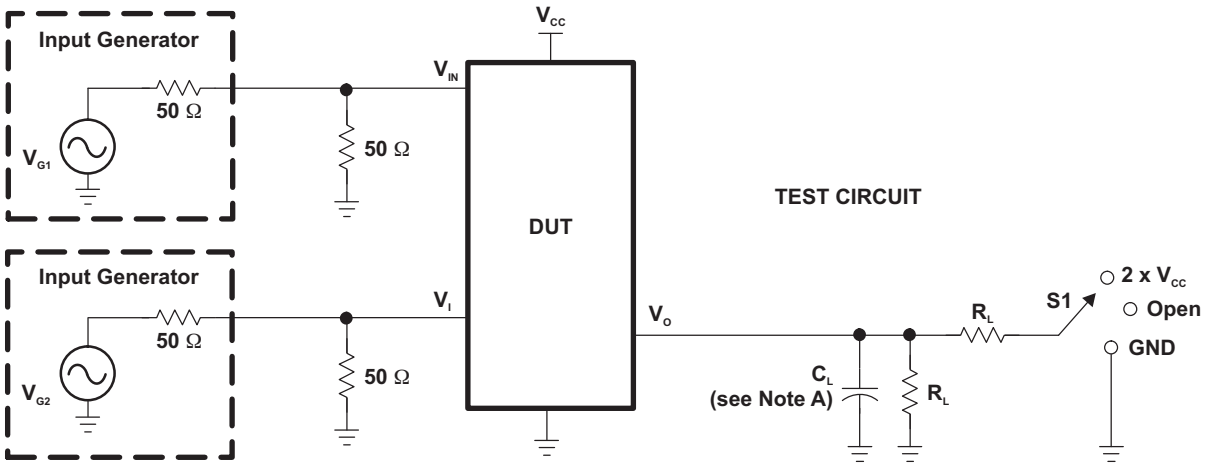
(1) V_{IN} and I_{IN} refer to control inputs. V_I, V_O, I_I, and I_O refer to data pins.
(2) All typical values are at V_{CC} = 3.3 V (unless otherwise noted), T_A = 25°C.
(3) For I/O ports, the parameter I_{OZ} includes the input leakage current.
(4) This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V_{CC} or GND.
(5) Measured by the voltage drop between A and B terminals at the indicated current through the switch. ON-state resistance is determined by the lower of the voltages of the two (A or B) terminals.

SWITCHING CHARACTERISTICS

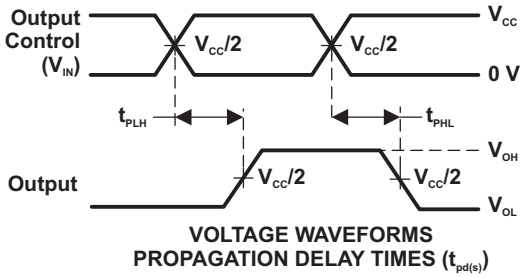
over recommended operating free-air temperature range (unless otherwise noted) (see Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CC} = 2.5 V ± 0.2 V		V_{CC} = 3.3 V ± 0.3 V		UNIT
			MIN	MAX	MIN	MAX	
t_{en}	$\overline{OE}$	A or B	1	10.5	1	9.5	ns
t_{dis}	$\overline{OE}$	A or B	1	8.5	1	9	ns

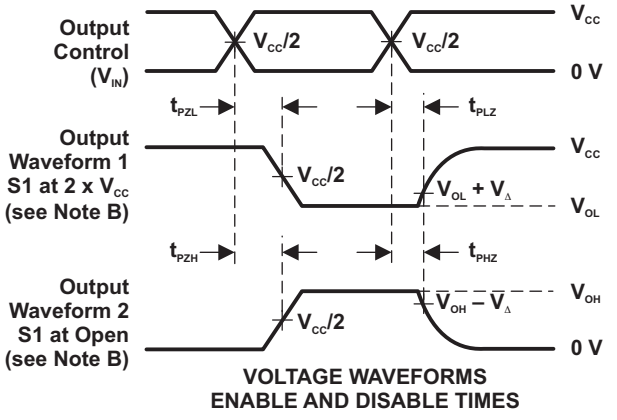
PARAMETER MEASUREMENT INFORMATION



TEST	V_{CC}	S1	R_L	V_I	C_L	V_Δ
$t_{pd(s)}$	2.5 V ± 0.2 V 3.3 V ± 0.3 V	Open Open	500 Ω 500 Ω	3.6 V or GND 5.5 V or GND	30 pF 50 pF	
t_{PLZ}/t_{PZL}	2.5 V ± 0.2 V 3.3 V ± 0.3 V	2 x V_{CC} 2 x V_{CC}	500 Ω 500 Ω	GND GND	30 pF 50 pF	0.15 V 0.15 V
t_{PHZ}/t_{PZH}	2.5 V ± 0.2 V 3.3 V ± 0.3 V	Open Open	500 Ω 500 Ω	3.6 V 5.5 V	30 pF 50 pF	0.15 V 0.15 V



VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES ($t_{pd(s)}$)



VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES

NOTES: A. C_L includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50 Ω, t_r ≤ 2.5 ns, t_f ≤ 2.5 ns.
D. The outputs are measured one at a time, with one transition per measurement.
E. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
F. t_{PZL} and t_{PZH} are the same as t_{en}.
G. t_{PLH} and t_{PHL} are the same as $t_{pd(s)}$. The tpd propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch nd the specified load capacitance, when driven by an ideal voltage source (zero output impedance).
H. All parameters and waveforms are not applicable to all devices.

Figure 2. Test Circuit and Voltage Waveforms

TYPICAL CHARACTERISTICS

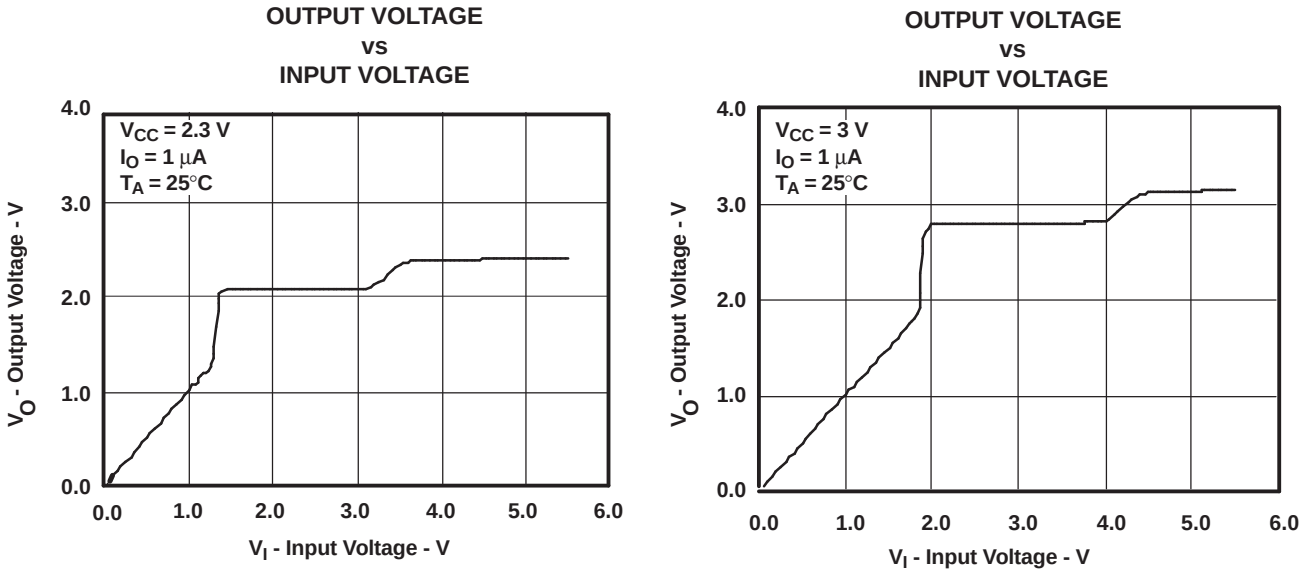


Figure 3. Data Output Voltage vs Data Input Voltage

TYPICAL CHARACTERISTICS

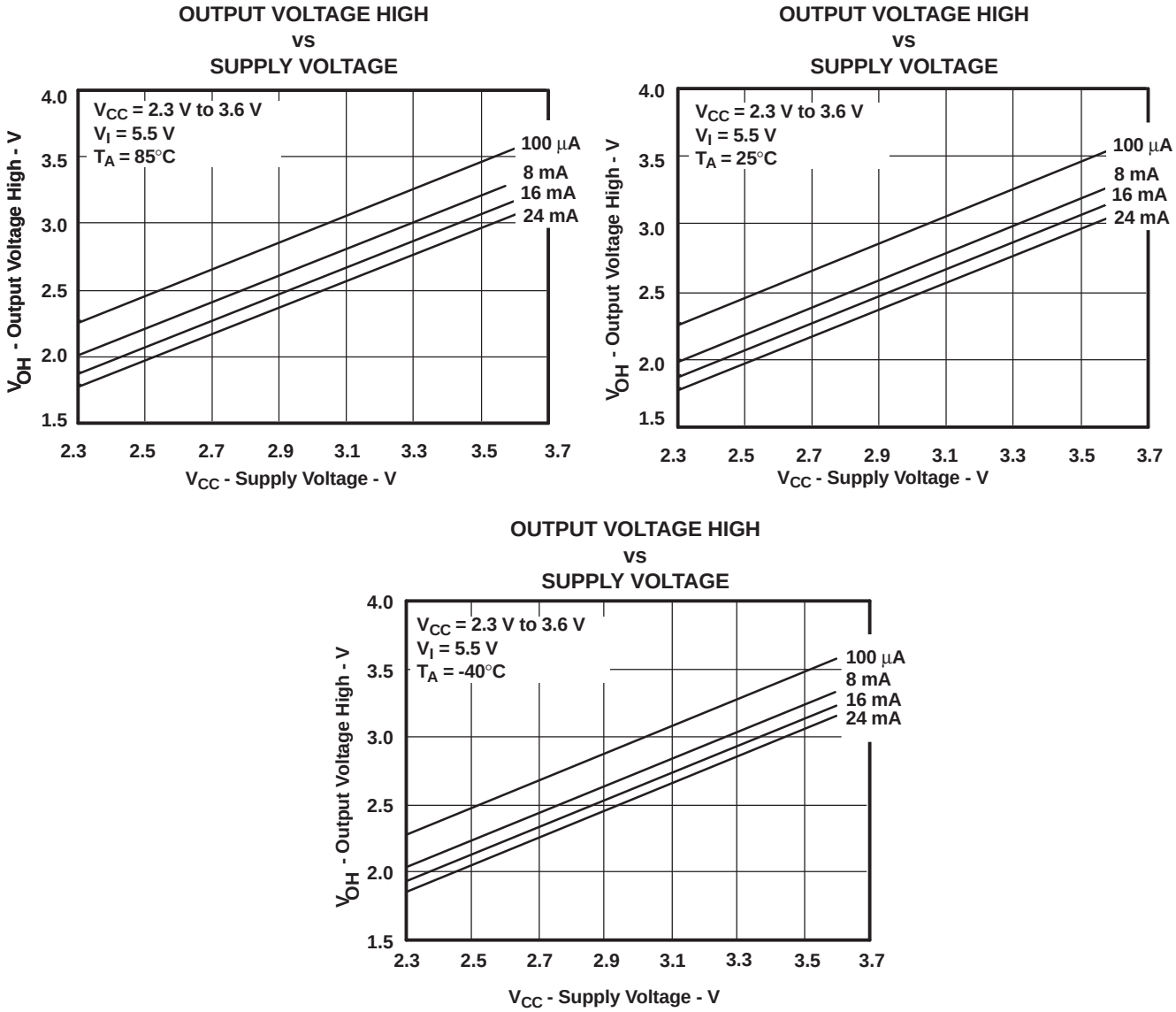


Figure 4. V_{OH} Values

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
CCB3T1G125QDCKRQ1	Active	Production	SC70 (DCK) | 5	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	72R
CCB3T1G125QDCKRQ1.B	Active	Production	SC70 (DCK) | 5	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	72R

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

OTHER QUALIFIED VERSIONS OF SN74CB3T1G125-Q1 :

- Catalog : SN74CB3T1G125

NOTE: Qualified Version Definitions:

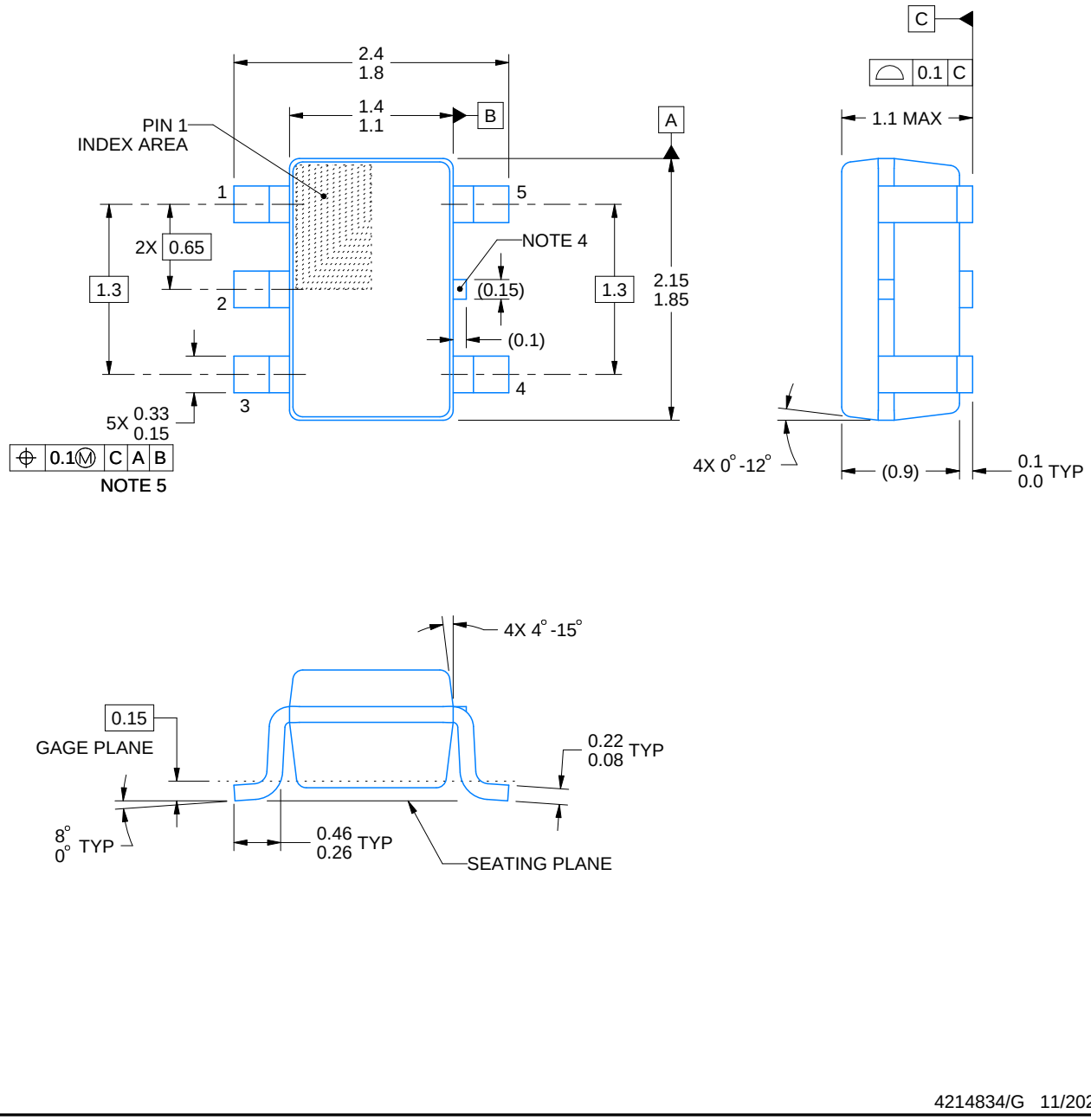
- Catalog - TI's standard catalog product

PACKAGE OUTLINE

DCK0005A

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



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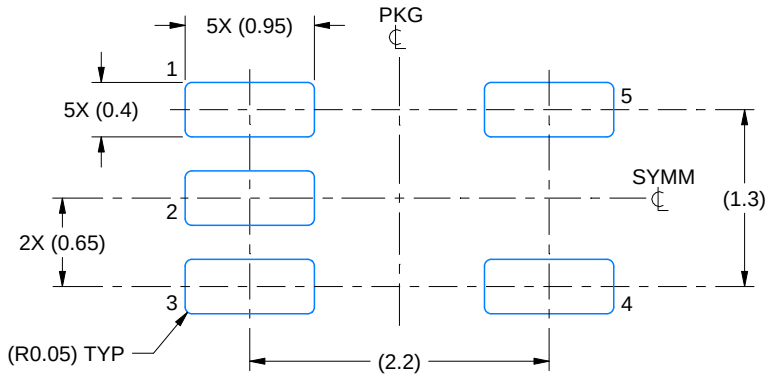
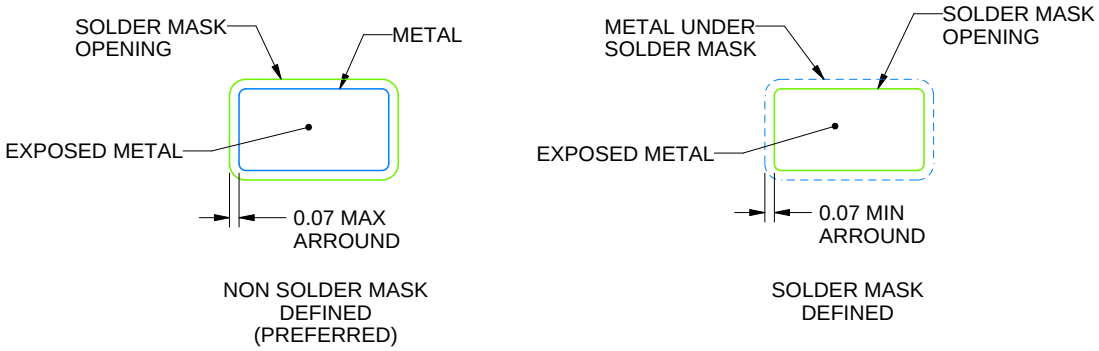
NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Refernce JEDEC MO-203.
4. Support pin may differ or may not be present.
5. Lead width does not comply with JEDEC.
6. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25mm per side



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:18X



SOLDER MASK DETAILS

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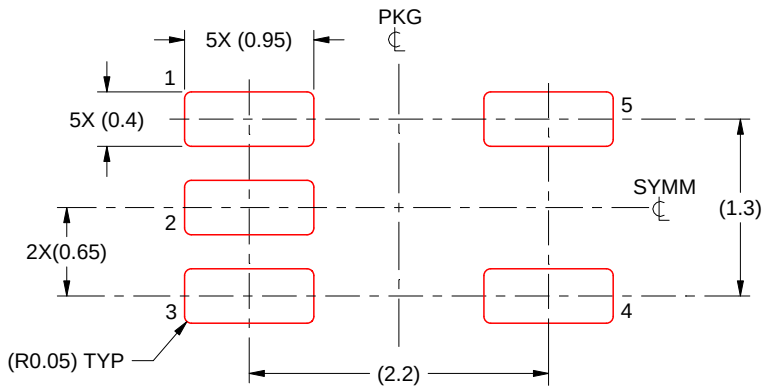
NOTES: (continued)

7. Publication IPC-7351 may have alternate designs.
8. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 THICK STENCIL
SCALE:18X

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NOTES: (continued)

9. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
10. Board assembly site may have different recommendations for stencil design.

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